

CD4514B, CD4515B Types

Data sheet acquired from Harris Semiconductor SCHS074A – Revised June 2003

CMOS 4-Bit Latch/4-to-16

Line Decoders

High-Voltage Types (20-Volt Rating) CD4514B Output "High" on Select CD4515B Output "Low" on Select

CD4514B and CD4515B consist of a 4-bit strobed latch and a 4-to-16-line decoder. The latches hold the last input data presented prior to the strobe transition from 1 to 0. Inhibit control allows all outputs to be placed at 0(CD4514B) or 1(CD4515B) regardless of the state of the data or strobe inputs.

The decode truth table indicates all combinations of data inputs and appropriate selected outputs.

These devices are similar to industry types MC14514 and MC14515.

The CD4514B and CD4515B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), and 16-lead small-outline packages (M and M96 suffixes).

LEAD TEMPERATURE (DURING SOLDERING):

Features:

- Strobed input latch
- Inhibit control
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package temperature range):

 $1 \text{ V at V}_{DD} = 5 \text{ V}$

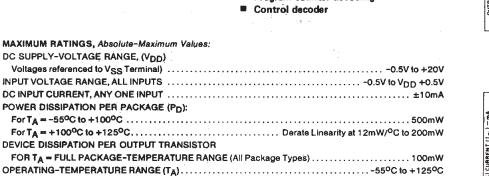
2 V at V_{DD} = 10 V

2.5 V at VDD = 15 V

- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics.
- Meets all requirements of JEDEC Tentative Standard No. 13B; "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

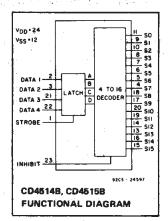
- Digital multiplexing
- Address decoding
- Hexadecimal/BCD decoding
- Program-counter decoding



STORAGE TEMPERATURE RANGE (Tstg).....-65°C to +150°C

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}$ C, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	VDD	LIN	UNITS		
OHAHAOTERISTIC	(V)	Min.	Max.	Citil	
Supply-Voltage Range (For T_A = Full Package- Temperature Range)		3	18	V	
Data Setup Time, t _S	5 10 15	150 70 40	_ _ _	ns	
Strobe Pulse Width, t _W	5 10 15	250 100 75	_ _ _	ņs	



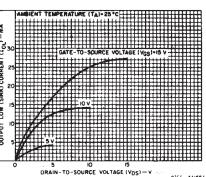


Fig. 1 — Typical output low (sink) current characteristics.

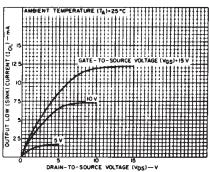


Fig. 2 — Minimum output low (sink) current characteristics.

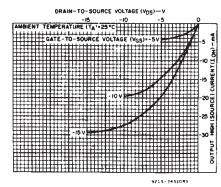


Fig. 3 — Typical output high (source) current characteristics.

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	IS	LIMI	LIMITS AT INDICATED TEMPERATURES (°C)							
ISTIC	Vo	VIN	VDD						+25		UNIT
	(V)	(V)	(V)	-55	-40	+85	+125	Min.	Тур.	Mex.	
Quiescent Device	_	0,5	5	5	5	150	150	_	0.04	5	
Current,	-	0,10	10	10	10	300	300	-	0.04	10	
IDD Max.	-	0,15	15	20	20	600	600	_	0.04	20	μΑ
	_	0,20	20	100	100	3000	3000		0.08	100	1
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1 .	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	-	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3 4	6.8	-	
Output High (Source) Current, IOH Min.	4.6	0,5	5	-0.64	~0.61	-0.42	-0.36	-0.51	-1		mA
	2.5	0,5	5	-2	1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:		0,5	5		0	.05		-	0	0.05	
Low Level, VOL Max.	_	0,10	10		0	.05		-	0	0.05	
AOF Max	-	0,15	15		0	.05		-	0	0.05	v
Output Voltage:	-	0,5	5		4	95		4.95	5	-	•
High-Level,		0,10	10		9	.95		9.95	10	-	
VOH Min.	-	0,15	15		14	.95		14.95	15	-	
Input Low	0.5, 4.5		5		1	.5		_	-	1.5	
Voltage,	1, 9	1	10			3		_	-	3	
VIL Max.	1.5,13.5	_	15			4		_	_	4	V
Input High Voltage, VIH Min.	0.5, 4.5		5		3	1.5		3.5		_	V
	1, 9	_	10			7		7	_		
	1.5,13.5	-	15		1	1		11		-	
Input Current	-	0,18	18	±0.1	±0.1	±1	±1	-	±10-5	±0.1	μΑ

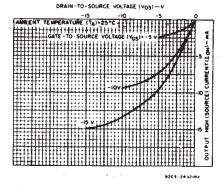


Fig. 4 — Minimum output high (source) current characteristics.

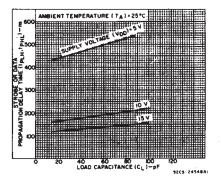


Fig. 5 — Typical strobe or data propagation delay time vs. load capacitance.

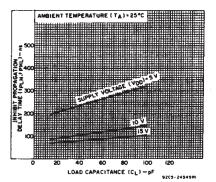


Fig. 6 — Typical inhibit propagation delay time vs. load capacitance.

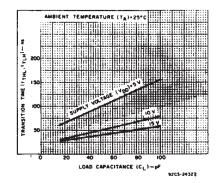


Fig. 7 — Typical low-to-high transition time vs. load capacitance.

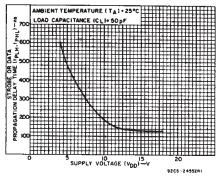


Fig. 8 — Typical strobe or data propagation delay time vs. supply voltage.

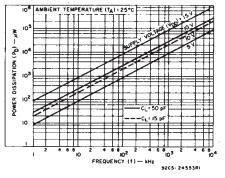


Fig. 9 — Typical power dissipation vs. frequency.

CD4514B, CD4515B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C; Input t_r , t_f = 20 ns, C_L = 50 pF, R_L = 200 $\kappa\Omega$

	TEST COND	TIONS	LIN	MITS	
CHARACTERISTIC		V _{DD}	Тур.	Max.	UNITS
Propagation Delay Time: tpHL, tpLH Strobe or Data		5 10 15	485 185 135	970 370 270	
Inhibit		5 10 15	250 110 85	500 220 170	ns
Transition Time, t _{TLH} , t _{THL}		5 10 15	100 50 40	200 100 80	
Minimum Strobe Pulse Width, t _W		5 10 15	125 50 40	250 100 75	ns
Minimum Data Setup Time, t _S		5 10 15	75 35 20	150 70 40	ns
Input Capacitance, CIN	Any Input	_	5	7.5	pF

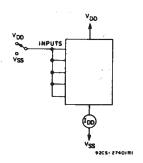


Fig. 10 - Quiescent device current test circuit.

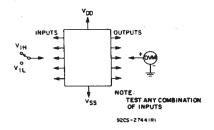


Fig. 11 + Input voltage test circuit.

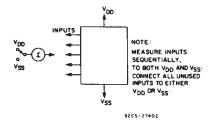


Fig. 12 - Input current test circuit.

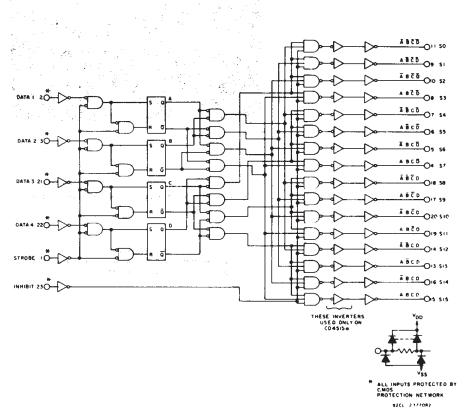
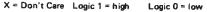


Fig. 13 - Logic diagram for CD4514B and CD4515B.

CD4514B, CD4515B Types

DECODE TRUTH TABLE (Strobe = 1)

INHIBIT		ECC		R	SELECTED OUTPUT
1141111511	D	С	В	A	CD4514B = Logic 1 (High) CD4515B = Logic 0 (Low)
0 0 0	0000	0000	0 0 1 1	0 1 0 1	\$0 \$1 \$2 \$3
0 0 0	0000	1 1 1	0 0 1	0 1 0 1	S4 S5 S6 S7
0 0 0	1 1 1	0000	0 0 1 1	0 1 0 1	S8 S9 S10 S11
0 0 0	1 1 1	1 1 1	0 0 1 1	0 1 0 1	\$12 \$13 \$14 \$15
1	х	х	х	х	All Outputs = 0, CD4514B All Outputs = 1, CD4515B



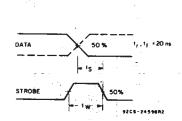
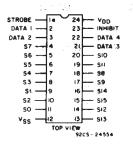
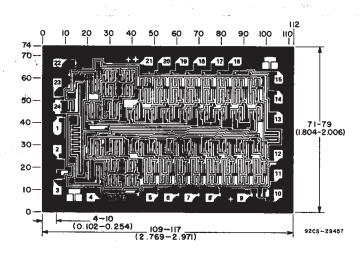


Fig. 14 — Waveforms for setup time and strobe pulse width.



CD4514B CD4515B TERMINAL ASSIGNMENT



Dimensions and Pad Layout for CD45158 Chip (Dimensions and pad layout for the CD45148 are identical)

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).





25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
7703201JA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	7703201JA CD4515BF3A	Samples
CD4514BE	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD4514BE	Samples
CD4514BEE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD4514BE	Samples
CD4514BF	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	CD4514BF	Samples
CD4514BF3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	CD4514BF3A	Samples
CD4514BM	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BM96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BM96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BM96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BMG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4514BM	Samples
CD4514BNSR	OBSOLETE	so so	NS	24		TBD	Call TI	Call TI	-55 to 125		
CD4514BPWR	OBSOLETE	TSSOP	PW	24		TBD	Call TI	Call TI	-55 to 125		
CD4515BE	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD4515BE	Samples
CD4515BEE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD4515BE	Samples
CD4515BF3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	7703201JA CD4515BF3A	Samples
CD4515BM	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples
CD4515BM96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples



PACKAGE OPTION ADDENDUM

25-Sep-2013

Orderable Device	Status	Package Type		Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
CD4515BM96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples
CD4515BM96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples
CD4515BME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples
CD4515BMG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4515BM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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25-Sep-2013

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD4514B, CD4514B-MIL, CD4515B, CD4515B-MIL:

● Catalog: CD4514B, CD4515B

• Military: CD4514B-MIL, CD4515B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4514BM96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD4514BM96G4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD4515BM96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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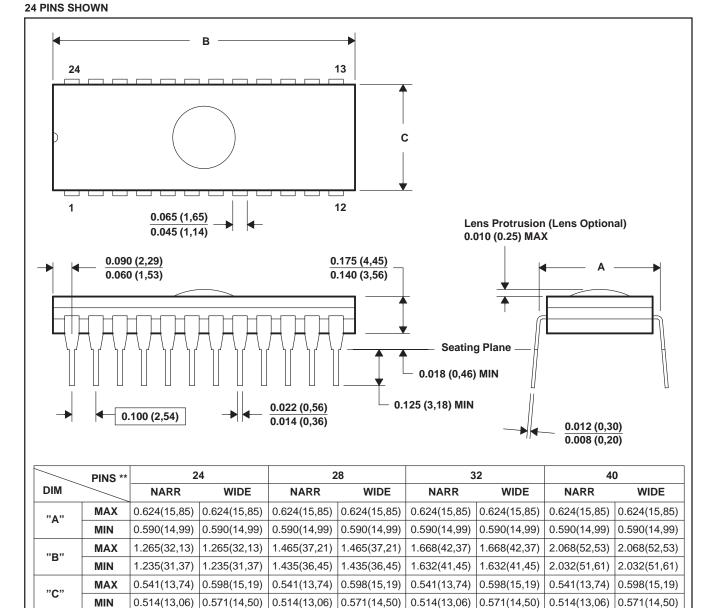
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4514BM96	SOIC	DW	24	2000	367.0	367.0	45.0
CD4514BM96G4	SOIC	DW	24	2000	367.0	367.0	45.0
CD4515BM96	SOIC	DW	24	2000	367.0	367.0	45.0

4040084/C 10/97

J (R-GDIP-T**)

CERAMIC DUAL-IN-LINE PACKAGE



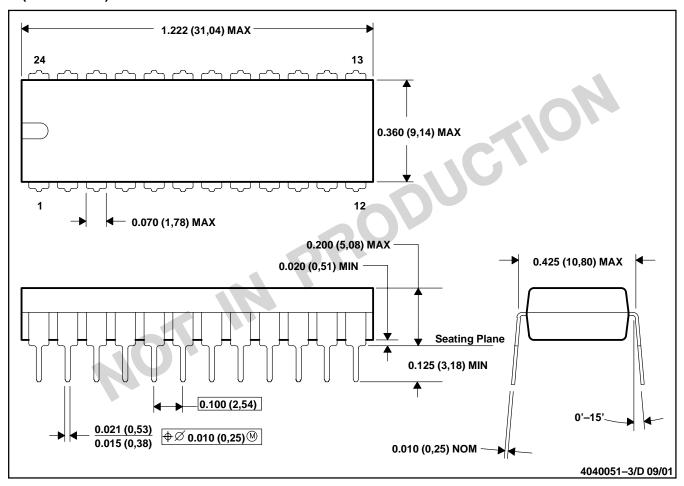
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



N (R-PDIP-T24)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-010

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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Products Applications

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